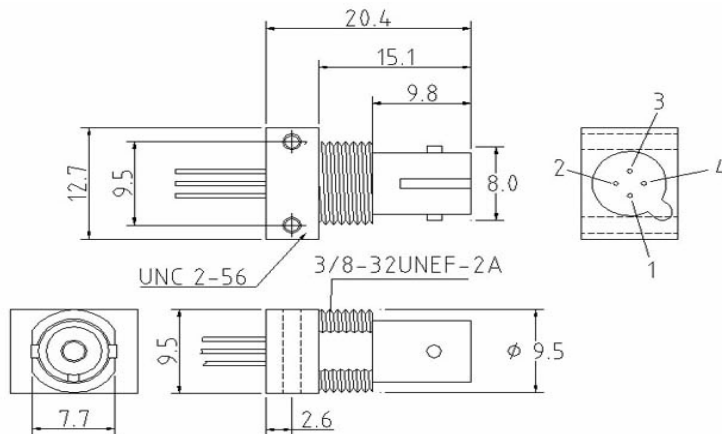


# UNF 14852 T

## Description:

Metal ST<sup>®</sup> Board-Mount Receptacle, threaded port with 3/8"-32 UNEF-2A, mounted with a 850nm medium power VCSEL-diode for standard applications with 50 or 62,5/125 $\mu$  graded index fibers over up to 4 km distance.

## Dimensions:



## Pinout:

- 1 = anode, pin shortened
- 2 = n.c.
- 3 = cathode
- 4 = case

## Supplied equipment:

- component
- nut 3/8"-32 UNEF-2A
- washer
- fixing screws 2-56
- dust cap

## Technical Data

Forward current .....	<b>10 mA</b> typ.
Peak current .....	<b>15 mA</b>
Power dissipation .....	<b>35 mW</b> max.
Forward voltage .....	<b>1,9 V</b> typ., 2,3 V max. at $I_F = 12$ mA
Reverse voltage .....	<b>10,0 V</b> max.
Cut-off frequency .....	<b>≥ 1 GHz</b>
Wavelength .....	<b>850 nm</b> typ.
Threshold current .....	<b>3,0 mA</b> typ., 6 mA max.
Series resistance .....	<b>40 Ohm</b> typ. at $I_F = 12$ mA
Fiber coupled power .....	<b>63 <math>\mu</math>W (-12,0 dBm)</b> min., 250 $\mu$ W (-9 dBm) max* <b>40<math>\mu</math>W (-14,0 dBm)</b> min. **
Material Barrel .....	<b>Nickel Silver</b>
Marking .....	<b>UNF14852T</b>
Operating temperature .....	<b>-20 to +85 °C</b>
Storage temperature .....	<b>-40 to +125 °C</b>

\* 50/125 $\mu$  GI-Faser,  $I_F=10$ mA,  $\theta = 25$  °C

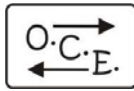
\*\* 50/125 $\mu$  GI-Faser,  $I_F=10$ mA, complete temperature range

**LASER RADIATION**

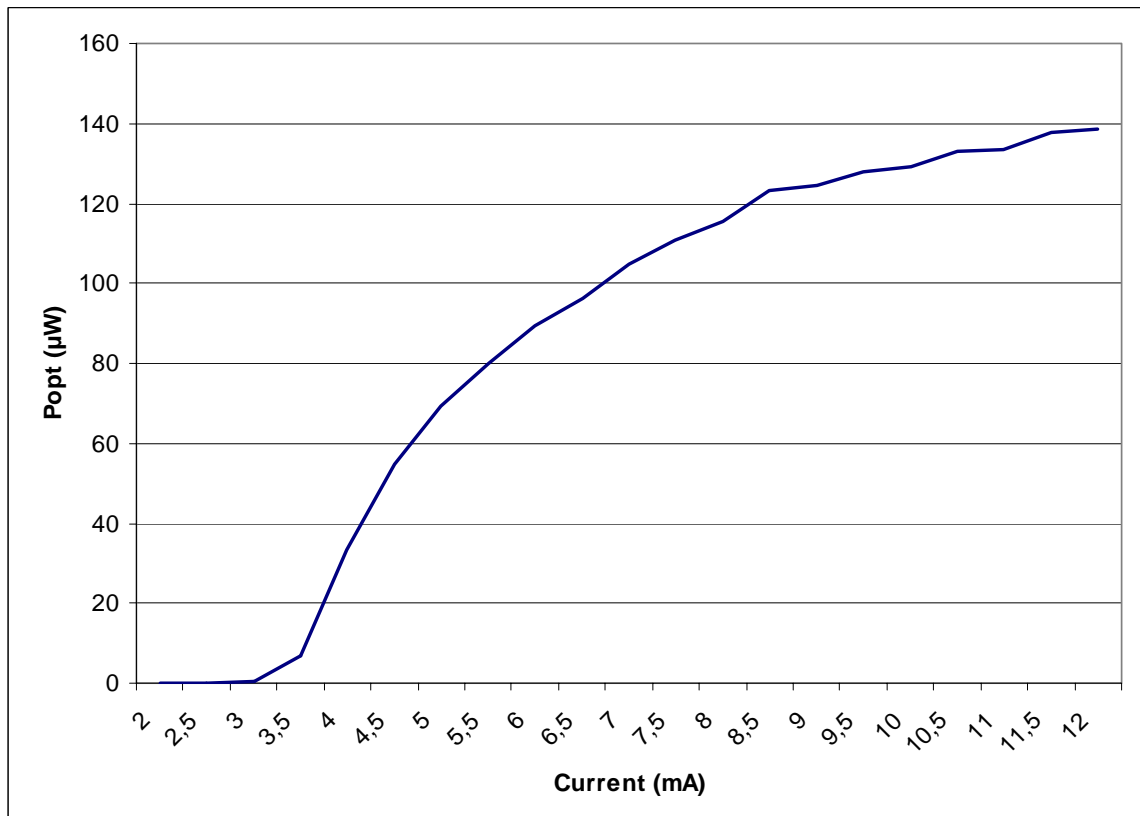
**DO NOT VIEW DIRECTLY WITH OPTICAL INSTRUMENTS**

**LASER CLASS 1M**

**according to DIN EN 60825-1:2001-11**



Gemessen mit einer 60m Leitung (62,5 $\mu$ ) bei 850 nm



Gemessen mit einer 60m Leitung (50 $\mu$ ) bei 850 nm

